Description

The CYHCPL3120 consists of a GaAsP LED optically coupled to an integrated circuit with a power output stage. This optocoupler is ideally suited for driving power IGBTs and MOSFETs used in motor control inverter applications. The high operating voltage range of the output stage provides the drive voltages required by gate controlled devices. The voltage and current supplied by this optocoupler makes it ideally suited for directly driving IGBTs with ratings up to 1200 V/100 A. For IGBTs with higher ratings, the CYHCPL3120 can be used to drive a discrete power stage which drives the IGBT gate.

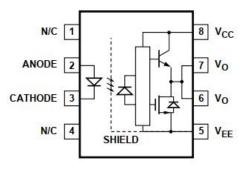
Features

- 2.0 A Minimum Peak Output Current
- 15 kV/µs Minimum Common Mode Rejection (CMR) at VCM = 1500 V
- 0.5 V Maximum Low Level Output Voltage (VOL) Eliminates Need for Negative Gate Drive
- ICC = 5 mA Maximum Supply Current
- Under Voltage Lock-Out Protection (UVLO) with Hysteresis
- Wide Operating VCC Range: 15 to 30 Volts
- 500 ns Maximum Switching Speeds
- Industrial Temperature Range: -40°C to 100°C

Applications

- Isolated IGBT/MOSFET Gate Drive
- AC and Brushless DC Motor Drives
- **Industrial Inverters**
- Switch Mode Power Supplies (SMPS)

Functional Diagram



Truth Table

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LED	V _{CC} -V _{EE} "Positive Going" (i.e.,Turn on)	V _{CC} -V _{EE} "Negative Going" (i.e.,Turn on)	Vo
OFF	0-30V	0-30V	Low
ON	0-11V	0-9.5V	Low
ON	11-13.5V	9.5-12V	Transition
ON	13.5-30V	12-30V	High



Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Value	Unit
Storage Temperature	T _{STG}	-55 to +125	℃
Operating Temperature	T _{OPR}	-40 to +100	℃
Lead Solder Temperature (10S 1.6mm below seating plane)	T _{SOL}	260	°C
Max Forward Input Current	I _{FM}	25	mA
Reverse Input Voltage	V _R	5.0	V
Peak Output Current	I _{O(PEAK)}	3.0	Α
Input Current(Rise/Fall time)	$t_{r(IN)}/t_{f(IN)}$	500	ns
Supply Voltage	V _{CC} -V _{SS}	0-30	V
Peak Output Voltage	V _{O(PEAK)}	0-V _{DD}	V

Note: When the maximum rating is exceeded, the device may be damaged. It is recommended that the device not work outside the recommended operating conditions, which may affect the function of the device. In addition, the reliability of components may be affected if the devices work in conditions beyond the recommended operating conditions for a long time. The maximum rating indicates stress class only.

Isolation Characteristics (Ta=25°C, unless specified otherwise**)**

Characteristics	Symbol	Condition	Min.	Тур.	Max.	Unit
Input-Output Momentary	V	RH<50%, TA=25℃	5000			V
Withstand Voltage	V _{ISO}	t=1min, 50H _Z	3000		V_{RMS}	
Resistance(Input-Output)	R _{ISO}	V _{I-O} =500V _{DC}		10 ¹¹		Ω
Capacitance(Input-Output)	C _{ISO}	f=1MH _Z , V _{I-O} =0V		1		pF

Recommended Operating Conditions

Parameter	Symbol	Min.	Max.	Units
Operating Temperature	T _A	-40	100	°C
Power Supply Voltage	V _{CC} -V _{SS}	0	30	V
Output Voltage	V _{O(PEAK)}	15	V_{DD}	V
Input Current (ON)	I _{F(ON)}	7	16	mA
Input Voltage (OFF)	V _{F(OFF)}	-3.0	0.8	V



Electrical Specification (Ta=25°C, V_{CC}=30V,V_{SS}=GND, unless specified otherwise)

Parameter	Symbol	Condition	Min.	Тур.*	Max.	Unit	
Input Forward Voltage	V _F	I _F =10mA	1.2	1.5	1.8	V	
Reverse Input Current	I _R	V _R =5V			0.1	uA	
High Lavel Output Compant	I _{OH}	$V_O = V_{DD} - 3V$	-1.0	-2.0	-2.5	А	
High Level Output Current		$V_O = V_{DD} - 6V$	-2.0		-2.5		
Lavel aval Ovtavt Comment		$V_O = V_{SS} + 3V$	1.0	2.0	2.5	_	
Low Level Output Current	I _{OL}	V _O =V _{EE} +6V	2.0		2.5	Α	
High Lavel Output Valtage	V	I _O =-2.5A , I _F =10mA	V _{CC} - 6.25V	V _{cc} - 2.5V		V	
High Level Output Voltage	V _{OH}	I _O =-100mA , I _F =10mA	V _{cc} - 0.25V	V _{cc} - 0.1V		V	
Low Level Output Voltage	V _{OL}	I _O =2.5A, I _F =0mA		V _{SS} + 2.5V	V _{SS} + 6.25V	V	
		I _O =100mA, I _F =0mA		V _{SS} + 0.1V	V _{SS} + 0.25V	V	
High Level Supply Current	I _{CCH}	I _F =7 to 16Ma,V _O =Open		2.8	3.8	mA	
Low Level Supply Current	I _{CCL}	$V_F = 0$ to 0.8V, $V_O = Open$		2.8	3.8	mA	
Threshold Input Current Low to High	I _{FLH}	V _O >5V, I _O =0A		2.3	5.0	mA	
Threshold Input Voltage High to Low	V_{FHL}	V _O < 5V, I _O =0A	0.8			V	
UVLO Threshold	$V_{\text{UVLO+}}$	$V_{O}>5V$, $I_{F}=10mA$	11.5	12.7	13.5	V	
OVLO TITESTICIO	V _{UVLO-}	$V_{O} < 5V$, $I_{F} = 10mA$	10.0	11.2	12.0	V	
UVLO Hysteresis	UVLO _{HYS}			1.5		V	

Switching Characteristics (Ta=25°C, V_{cc}=30V,V_{ss}=GND, unless specified otherwise)

Characteristics	Symbol	Condition	Min.	Тур.	Max.	Unit
Propagation Delay Time to Output HIGH Leve	T_{PLH}		150	255	400	ns
Propagation Delay Time to Output LOW Level	T _{PHL}		150	275	400	ns
Pulse Width Distortion	PWD	C_g =10nF, f=10kHZ, R_g =10 Ω Duty Cycle=50%		20	100	ns
Propagation Delay Difference Between Any Two Part of channels	T _{PHL} -T _{PLH}	I _F =7mA to 16mA V _{CC} = 30V,V _{SS} =Ground	-250		250	ns
Rise Time	T _r			60		ns
Fall Time	T _f			60		ns
Common Mode Transient Immunity (at Output HIGH Level)	CMH	$T_A = 25$ °C, $I_F = 7$ to 16mA, $V_{CM} = 2000V, V_{CC} = 30V$	35	50		kV/μs
Common Mode Transient Immunity (at Output LOW Level)	CML	$T_A = 25^{\circ}C, V_F = 0V$ $V_{CM} = 2000V, V_{CC} = 30V$	35	50		kV/µs



Typical Performance Curves

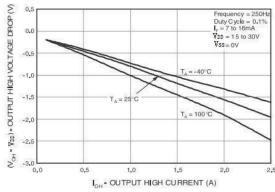


Fig.1:Output Voltage vs Output Current

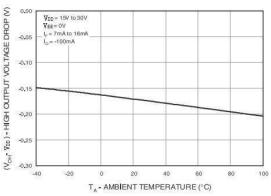


Fig.2:Output Voltage vs Temperature

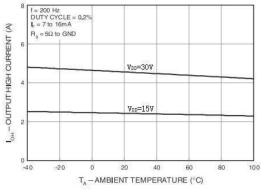


Fig.3:Output High Current vs Temperature

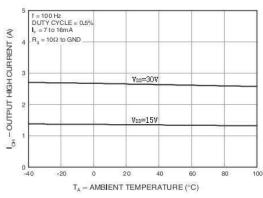


Fig.4: Output Current vs Temperature

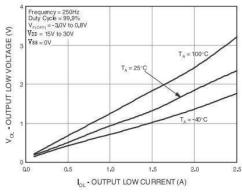


Fig.5:Output Low Voltage vs Output Low Current

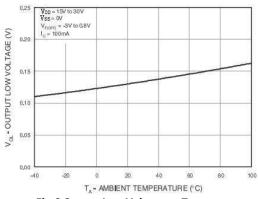


Fig.6:Output Low Voltage vs Temperature

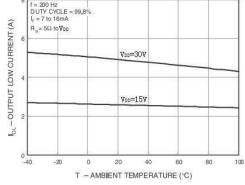


Fig.7:Output Current vs Temperature

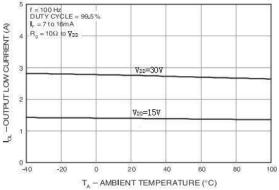
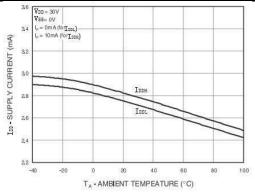


Fig.8:Output Low Current vs Temperature



CYHCPL3120

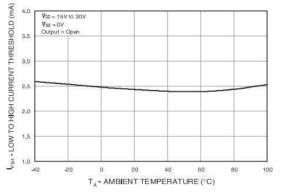


 $I_p = 10 \text{ mA (for I one)}$ $I_p = 0 \text{ m A (for I one)}$ $V_{SS} = 0 \text{ , } T_A = 25 \text{ °C}$ Ipp - SUPPLY CURRENT (mA) Iddh IDDI 15

V - SUPPLY VOLTAGE (V)

Fig.9:Supply Current vs Temperature

Fig.10: Supply Current vs Supply Voltage



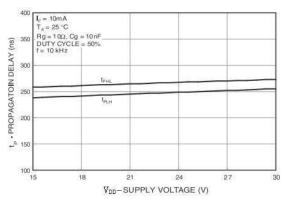
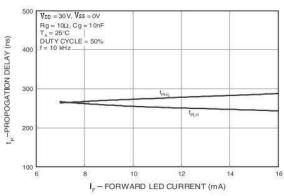


Fig.11:Low to High Current vs Temperature

Fig.12:Propagation Delay vs Supply Voltage



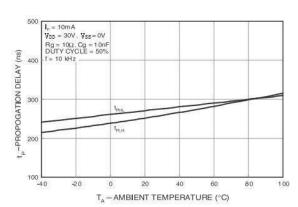
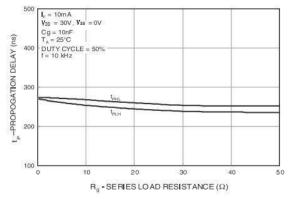


Fig.13: Propagation Delay vs I_F

Fig.14: Propagation Delay vs Temperature



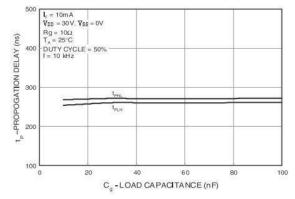
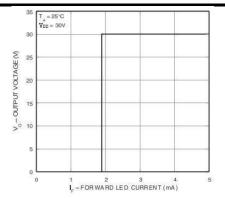


Fig.15: Propagation Delay vs R_S

Fig.16: Propagation Delay vs Cg



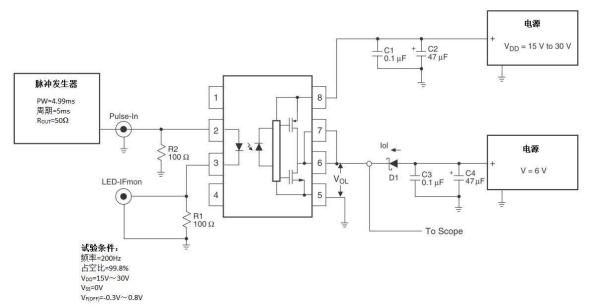
CYHCPL3120



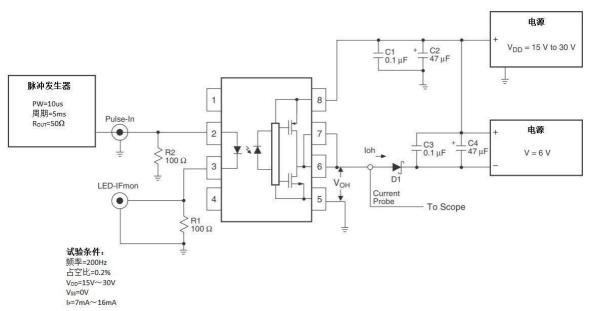
T_A = 100 C C T_A = -40 C T_A

Fig.17:Output Current vs I_F

Fig.18:Forward Current vs Forward Voltage

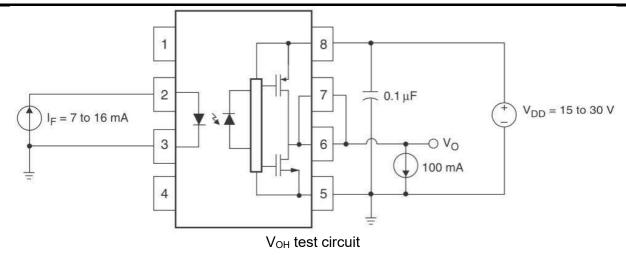


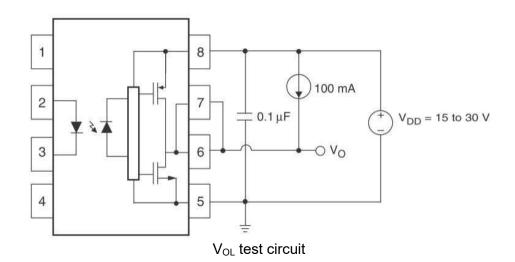
I_{OL} test circuit

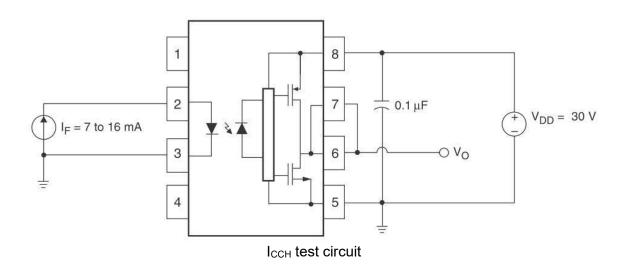


I_{OH} test circuit

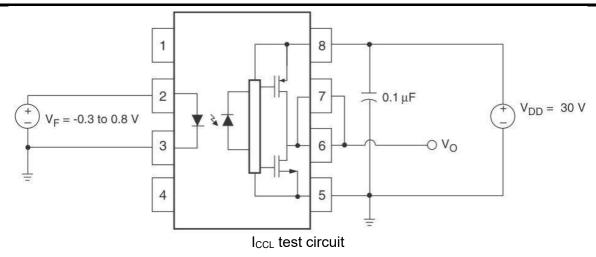


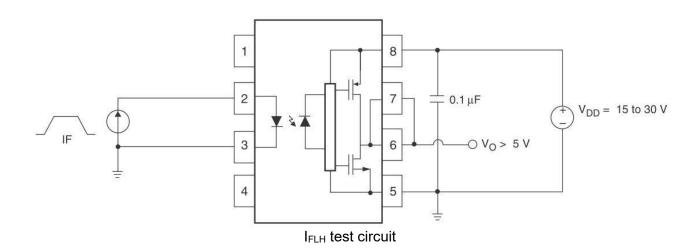


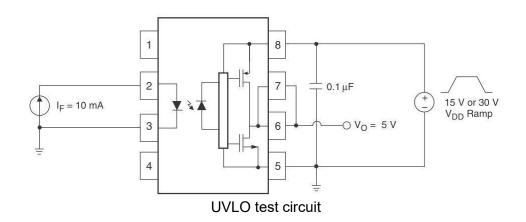




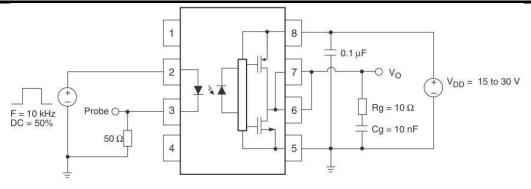


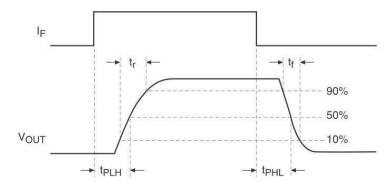




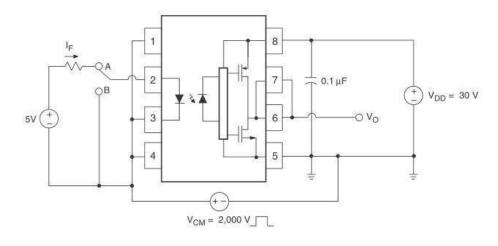


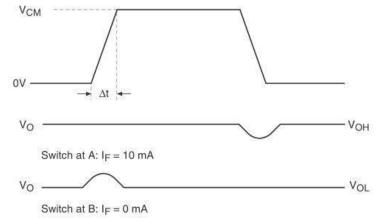






 $t_{\text{PHL}},\ t_{\text{PLH}},\ t_{\text{R}},\ t_{\text{F}}$ test circuit

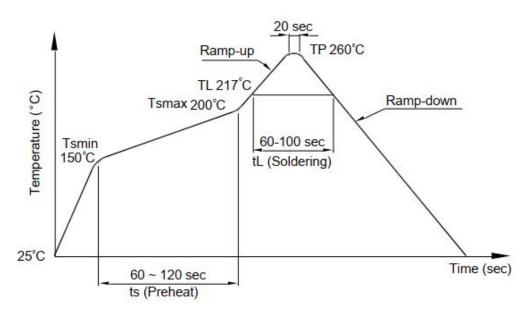




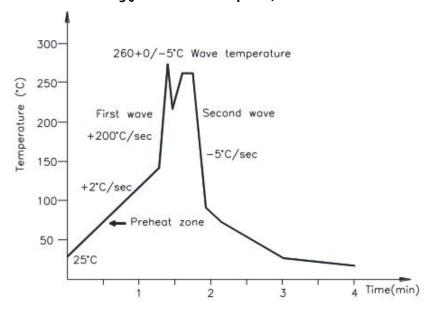
CRM test circuit

Temperature Profile of Soldering

1. Reflow soldering(JEDEC-STD-020C compliant)



2. Wave soldering(jedec22a111 compliant)



3. Hand soldering by soldering iron

Allow single lead soldering in every single process. One time soldering is recommended Temperature: $380+0/-5^{\circ}C$

Time: 3 sec max.



Attention:

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